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February 2013

BSS84

P-Channel Enhancement Mode Field-Effect Transistor

Features

- -0.13 A, -50 V, $R_{DS(ON)} = 10 \Omega$ at $V_{GS} = -5 V$
- Voltage-Controlled P-Channel Small-Signal Switch
- High-Density Cell Design for Low R_{DS(ON)}
- High Saturation Current





Description

This P-channel enhancement-mode field-effect transistor is produced using Fairchild's proprietary, high cell density, DMOS technology. This very high density process minimizes on-state resistance and to provide rugged and reliable performance and fast switching. The BSS84 can be used, with a minimum of effort, in most applications requiring up to 0.13 A DC and can deliver current up to 0.52 A. This product is particularly suited to low-voltage applications requiring a low-current high-side switch.

Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Symbol	Parameter		Ratings	Unit
V_{DSS}	Drain-Source Voltage		-50	V
V_{GSS}	Gate-Source Voltage		±20	V
I _D	Drain Current ⁽¹⁾	Continuous	-0.13	Α
		Pulsed	-0.52	Α
_	Maximum Power Dissipation ⁽¹⁾		0.36	W
P_D	Derate Above 25°C		2.9	mW / °C
T _J , T _{STG}	Operating and Storage Junction Temperature Range		-55 to +150	°C
TL	Maximum Lead Temperature for Soldering Purposes 1/16" from Case for 10 Seconds		300	°C

Thermal Characteristics

$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient ⁽¹⁾	350	°C/W

Note:

1. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JA}$ is guaranteed by design, while $R_{\theta JA}$ is determined by the user's board design.



a) 350°C/W when mounted on a minimum pad

Scale 1: 1 on letter-size paper.

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
SP	BSS84	7"	8mm	3000

Electrical Characteristics(2)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Off Char	acteristics					
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_{D} = -250 \mu\text{A}$	-50			V
ΔBV_{DSS}	Breakdown Voltage Temperature	$I_D = -250 \mu A$		4.0		
<u></u> ΔT _J	Coefficient	Referenced to 25°C		-4 8		mV / ℃
		$V_{DS} = -50 \text{ V}, V_{GS} = 0 \text{ V}$			-15	uΑ
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -50 \text{ V}, V_{GS} = 0 \text{ V},$				^
	· ·	T _J = 125°C			-60	μΑ
I_{GSS}	Gate-Body Leakage.	$V_{GS} = \pm 20 \text{ V}, \ V_{DS} = 0 \text{ V}$			±10	nA
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_{D} = -250 \mu\text{A}$	-50			V
On Char	acteristics ⁽²⁾					
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = -1$ mA	-0.8	-1.7	-2	V
V _{GS(TH)}	Gate Threshold Voltage	$I_D = -1 \text{ mA},$				1/100
TJ	Temperature Coefficient	Referenced to 25°C		3		mV / ℃
1	Static Drain–Source On–Resistance	$V_{GS} = -5 \text{ V}, I_D = -0.10 \text{ A}$		1.2	10.0	Ω
R _{DS(on)}		$V_{GS} = -5 \text{ V}, I_D = -0.10 \text{ A},$		1.9	17.0	Ω
		T _J = 125°C		1.9	17.0	22
I _{D(on)}	On–State Drain Current	$V_{GS} = -5 \text{ V}, V_{DS} = -10 \text{ V}$	-0.6			Α
g FS	Forward Transconductance	$V_{DS} = -25 \text{ V}, I_{D} = -0.10 \text{ A}$	0.05	0.60		S
_	Characteristics				1	
C _{ISS}	Input Capacitance	$V_{DS} = -25 \text{ V},$		73		pF
Coss	Output Capacitance	$V_{GS} = 0 V$		10		pF
C_{RSS}	Reverse Transfer Capacitance	f = 1.0 MHz		5		pF
R _G	Gate Resistance	$V_{GS} = -15 \text{ mV}, f = 1.0 \text{ MHz}$		9		Ω
Switchin	g Characteristics ⁽²⁾					
t _{d(on)}	Turn-On Delay			2.5	5.0	ns
t _r	Turn-On Rise Time	$V_{DD} = -30 \text{ V}, I_D = -0.27 \text{ A},$		6.3	13.0	ns
t _{d(off)}	Turn-Off Delay	$V_{GS} = -10 \text{ V}, R_{GEN} = 6$		10	20	ns
t _f	Turn-Off Fall Time			4.8	9.6	ns
Q_g	Total Gate Charge	$V_{DS} = -25 \text{ V}, I_{D} = -0.10 \text{ A},$		0.9	1.3	nC
Q_{gs}	Gate-Source Charge	$V_{GS} = -25 \text{ V}, \text{ 1D} = -0.10 \text{ A},$ $V_{GS} = -5 \text{ V}$		0.2		nC
Q_{gd}	Gate-Drain Charge			0.3		nC
Drain-Sc	ource Diode Characteristics and	Maximum Ratings				
Is	Maximum Continuous Drain-Source Diode Forward Current		. //		-0.13	Α
V _{SD}	Drain-Source Diode Forward Voltage	V _{GS} = 0 V, I _S = - 0.26 A ⁽²⁾		-0.8	-1.2	V
t _{RR}	Diode Reverse-Recovery Time	I _F = -0.1 A,		10		ns
	Diode Reverse-Recovery Charge d _{iF} / d _t = 100 A / µs ⁽²⁾		-	3		

Note:

2. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

Typical Characteristics

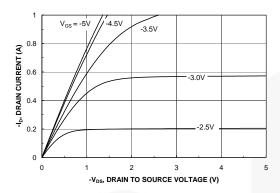


Figure 1. On-Region Characteristics

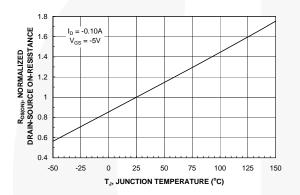


Figure 3. On-Resistance Variation with Temperature

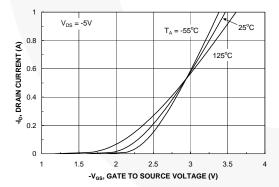


Figure 5. Transfer Characteristics

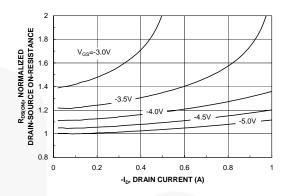


Figure 2. On-Resistance Variation with Drain Current and Gate Voltage

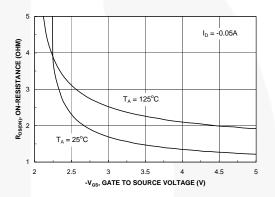


Figure 4. On-Resistance Variation with Gate-to-Source Voltage

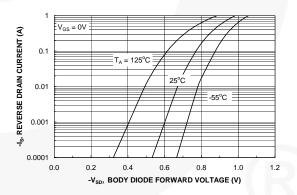


Figure 6. Body Diode Forward Voltage Variation with Source Current and Temperature

Typical Characteristics (Continued)

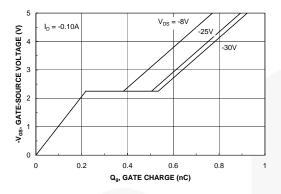


Figure 7. Gate Charge Characteristics

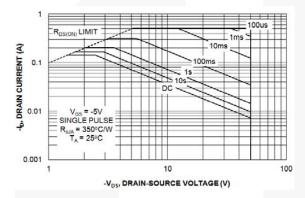


Figure 9. Maximum Safe Operating Area

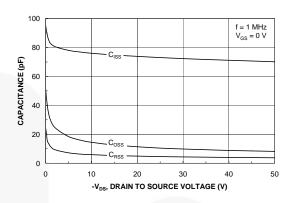


Figure 8. Capacitance Characteristics

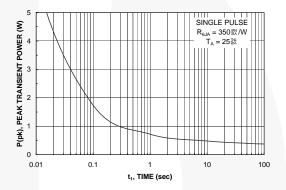


Figure 10. Single-Pulse Maximum Power Dissipation

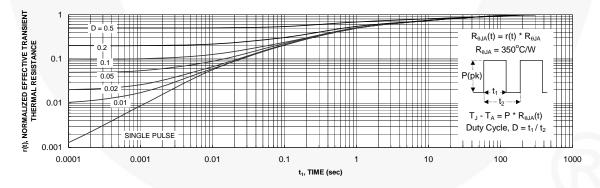


Figure 11. Transient Thermal Response Curve

Thermal characterization performed using the conditions described on page 1. Transient thermal response will change depending on the circuit board design.

Physical Dimension

SOT-23 3L

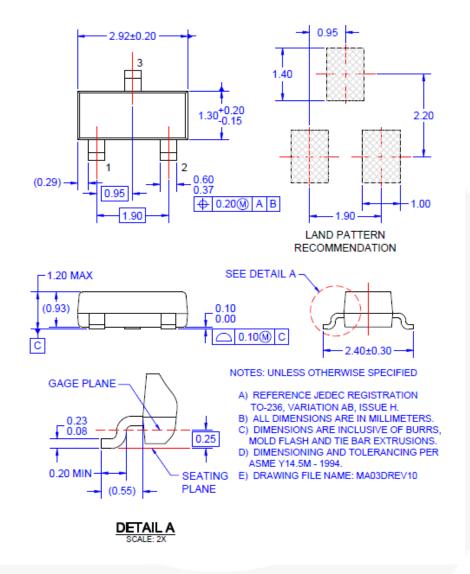


Figure 12. 3-LEAD, SOT23, JEDEC TO-236, LOW PROFILE

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